TH58BVG2S3HTAI0

TH58BVG2S3HTAI0 Information

For Reference Only

Part Number TH58BVG2S3HTAI0
Manufacturer Toshiba Semiconductor and Storage
Category Integrated Circuits (ICs)
Memory
Description IC EEPROM 4GBIT 25NS 48TSOP
Package 48-TFSOP (0.724", 18.40mm Width)

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

TH58BVG2S3HTAI0 Specifications

Manufacturer Part Number	TH58BVG2S3HTAI0
Manufacturer	Toshiba Semiconductor and Storage
Category	Integrated Circuits (ICs)
	Memory
Package	48-TFSOP (0.724", 18.40mm Width)
Series	Benand?
Memory Type	Non-Volatile
Memory Format	EEPROM
Technology	EEPROM - NAND
Memory Size	4Gb (512M x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	25ns
Access Time	25ns
Voltage - Supply	2.7 V ~ 3.6 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-TFSOP (0.724", 18.40mm Width)
Supplier Device Package	48-TSOP I
	Report errors?

TH58BVG2S3HTAI0 Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

TH58BVG2S3HTAI0 Payment Methods

TH58BVG2S3HTAI0 Shipping Methods

If you have any question about TH58BVG2S3HTAI0, please do not hesitate to contact us!
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